## SUPPORTING INFORMATION

## Phosphonic Acid Modification of the Electron Selective Contact: Interfacial Effects in Perovskite Solar Cells

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	φ [eV]
Control	4.8 ± 0.1
pCN-BPA	$4.5 \pm 0.1$
BPA	$4.3 \pm 0.1$
DEA-P-CNVPA	$4.1 \pm 0.1$

 Table S1. Work function in eV for control and phosphonic acid modified substrates.

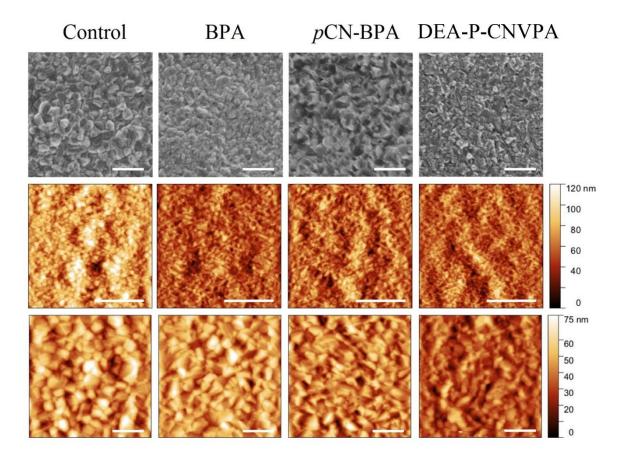


Figure S1. SEM (top row) and AFM (middle and bottom rows) of control and phosphonic acid modified substrates. Prior to device fabrication, the control was treated with UV-Ozone for 15 min, while the tin oxide was modified with 0.05 mM of phosphonic acid in ethanol for 3 h. Scale bar is 500 nm for the top and bottom rows, and 2  $\mu$ m for the middle row.

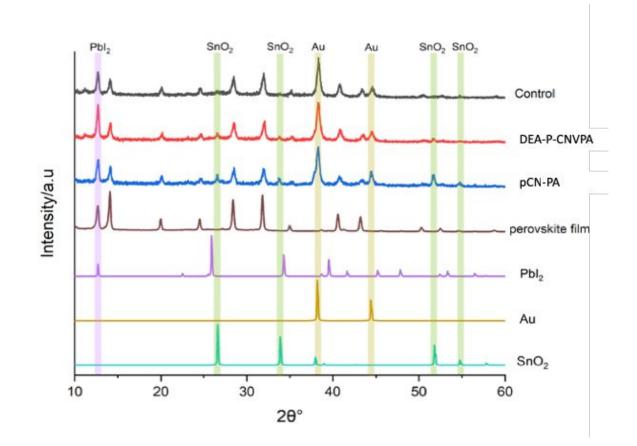


Figure S2. X-ray diffraction patterns of full devices of control, 020A and 038A with reference patterns.

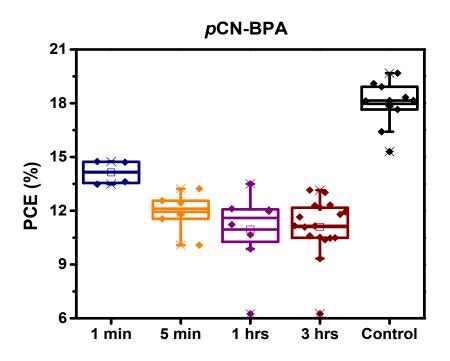
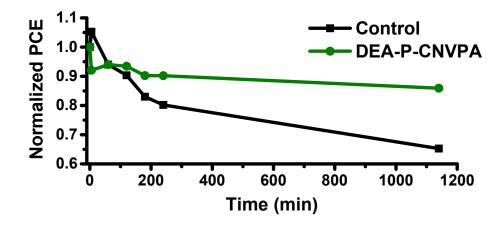


Figure S3. Power conversion efficiency as a function of dipping time for *p*CN-BPA.



**Figure S4**. Normalized PCE for control and modified devices as a function of time resting in inert atmosphere. Prior to device fabrication, the control was treated with UV-Ozone for 15 min, while the tin oxide was modified with 0.05 mM DEA-P-CNVPA in ethanol for 1 h.

	SnO <sub>2</sub> Control	BPA	pCN-BPA	DEA-P- CNVPA
$ heta_{water}$ / °	5.4 ± 2.9	27.7 ± 5.3	$37.8 \pm 3.4$	47.9 ± 2.1
$ heta_{diiodomethane}/\circ$	29.6 ± 3.8	$25.9 \pm 3.4$	$20.3 \pm 3.4$	21.4 ± 3.4
$\gamma_{polar}$ / mJ cm <sup>-2</sup>	31.8 ± 1.1	$24.7\pm2.3$	$19.0 \pm 1.8$	$14.0 \pm 1.2$
$\gamma_{disp}$ / mJ cm <sup>-2</sup>	$44.4 \pm 1.6$	$45.8 \pm 1.2$	$47.7 \pm 1.0$	47.4 ± 1.1
$\gamma_{total}$ / mJ cm <sup>-2</sup>	76.2 ± 1.9	$70.5\pm2.6$	$66.7 \pm 2.1$	61.3 ± 1.0

**Table S2**. Surface modified<sup>*a*</sup> tin oxide contact angles using water and diiodomethane, with the calculated dispersive, polar, and total surface energy.<sup>*b*</sup> The control sample was UV-Ozone treated prior to measurement.

 ${}^{a}$ SnO<sub>2</sub> was UV-ozone cleaned and modified by dipping in a 0.05 mM PA sol. in ethanol for 1-3 h and rinsed with EtOH.  ${}^{b}$ The surface energy error was propagated from the contact angle measurements and does not include error from literature values.